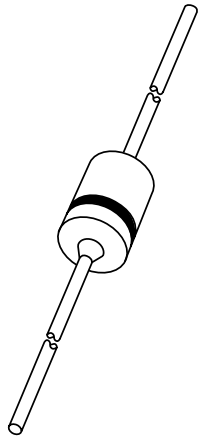


# DATA SHEET



## **BAV10** High-speed diode

Product specification  
Supersedes data of April 1996

1996 Sep 16

## High-speed diode

## BAV10

## FEATURES

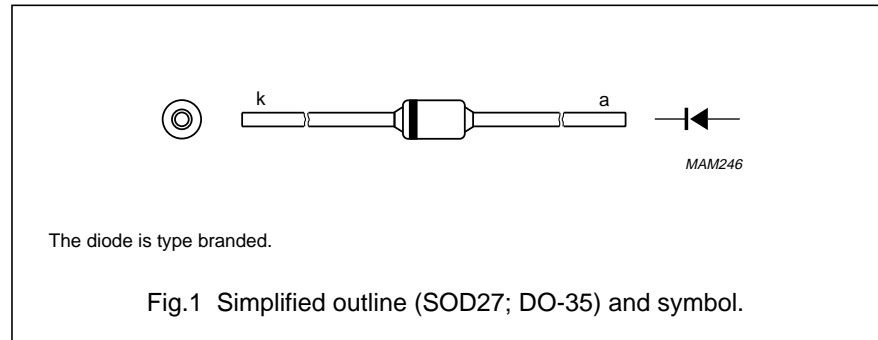
- Hermetically sealed leaded glass SOD27 (DO-35) package
- High switching speed: max. 6 ns
- General application
- Continuous reverse voltage: max. 60 V
- Repetitive peak reverse voltage: max. 60 V
- Repetitive peak forward current: max. 600 mA.

## APPLICATIONS

- High-speed switching.

## DESCRIPTION

The BAV10 is a high-speed switching diode fabricated in planar technology, and encapsulated in the hermetically sealed leaded glass SOD27 (DO-35) package.



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage		–	60	V
$V_R$	continuous reverse voltage		–	60	V
$I_F$	continuous forward current	see Fig.2; note 1	–	300	mA
$I_{FRM}$	repetitive peak forward current		–	600	mA
$I_{FSM}$	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 $t = 1\ \mu\text{s}$ $t = 100\ \mu\text{s}$ $t = 1\ \text{s}$	–	9 3 1	A A A
$P_{tot}$	total power dissipation	$T_{amb} = 25\text{ °C}$ ; note 1	–	350	mW
$T_{stg}$	storage temperature		–65	+200	°C
$T_j$	junction temperature		–	200	°C

## Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

## High-speed diode

## BAV10

**ELECTRICAL CHARACTERISTICS**

$T_j = 25\text{ °C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_F$	forward voltage	see Fig.3			
		$I_F = 10\text{ mA}$	–	750	mV
		$I_F = 200\text{ mA}$	–	1.0	V
		$I_F = 500\text{ mA}$	–	1.25	V
		$I_F = 200\text{ mA}; T_j = 100\text{ °C}$	–	950	mV
$I_R$	reverse current	see Fig.5			
		$V_R = 60\text{ V}$	–	100	nA
		$V_R = 60\text{ V}; T_j = 150\text{ °C}$	–	100	$\mu\text{A}$
$C_d$	diode capacitance	$f = 1\text{ MHz}; V_R = 0$ ; see Fig.6	–	2.5	pF
$t_{rr}$	reverse recovery time	when switched from $I_F = 400\text{ mA}$ to $I_R = 400\text{ mA}$ ; $R_L = 100\ \Omega$ ; measured at $I_R = 40\text{ mA}$ ; see Fig.7	–	6	ns
$V_{fr}$	forward recovery voltage	when switched from $I_F = 400\text{ mA}$ ; $t_r = 30\text{ ns}$ ; see Fig.8	–	2	V
		when switched from $I_F = 400\text{ mA}$ ; $t_r = 10\text{ ns}$ ; see Fig.8	–	1.5	V

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length 10 mm; note 1	500	K/W

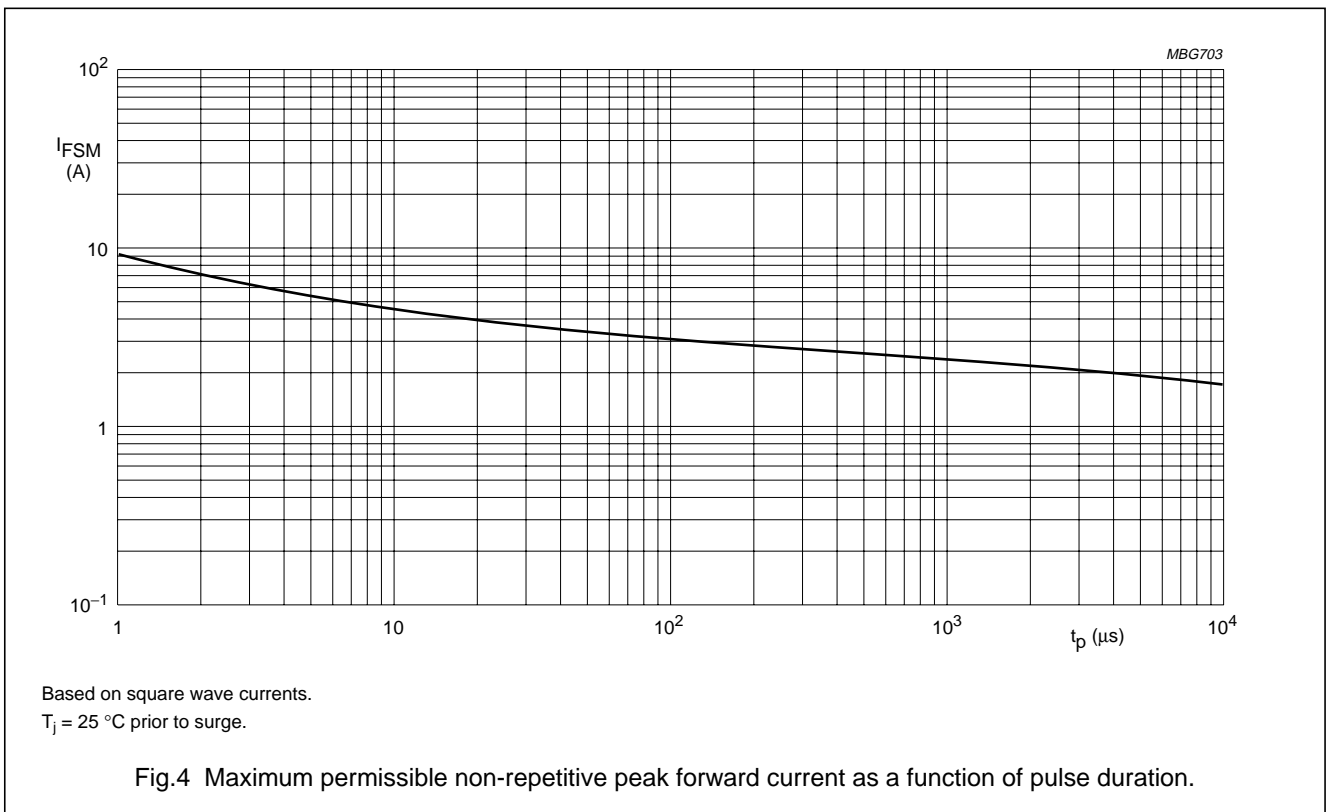
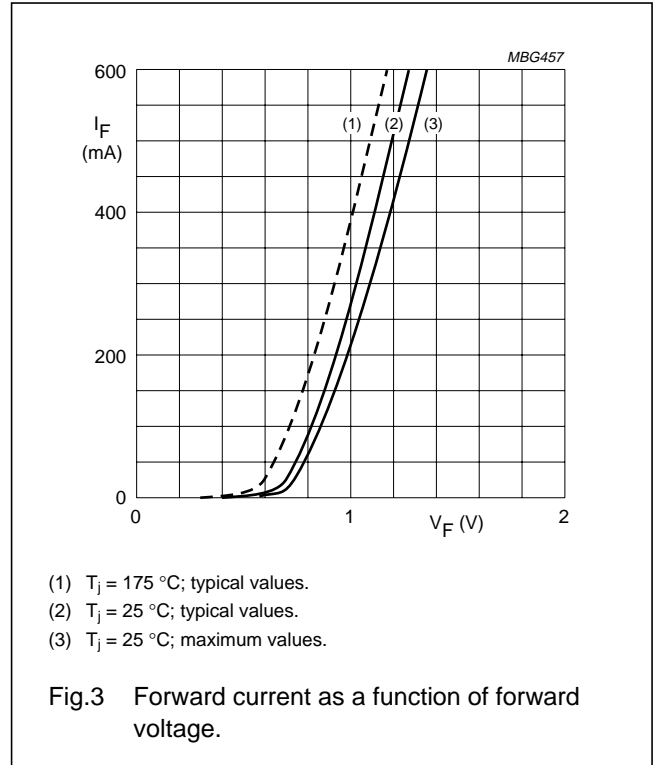
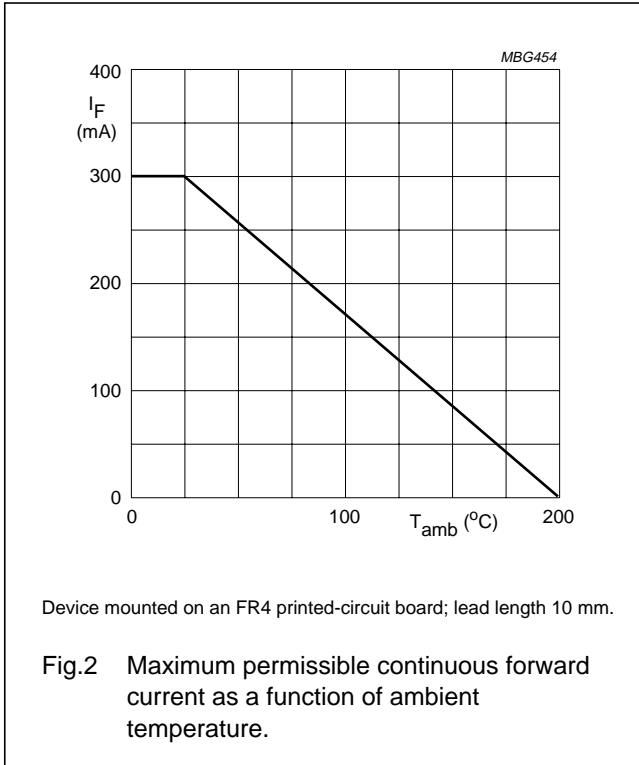
**Note**

1. Device mounted on a printed circuit-board without metallization pad.

High-speed diode

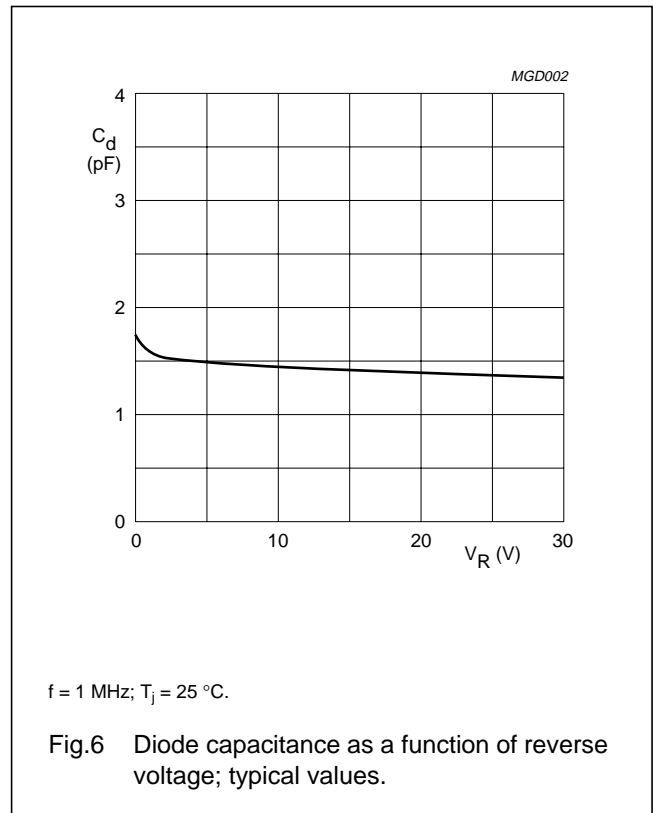
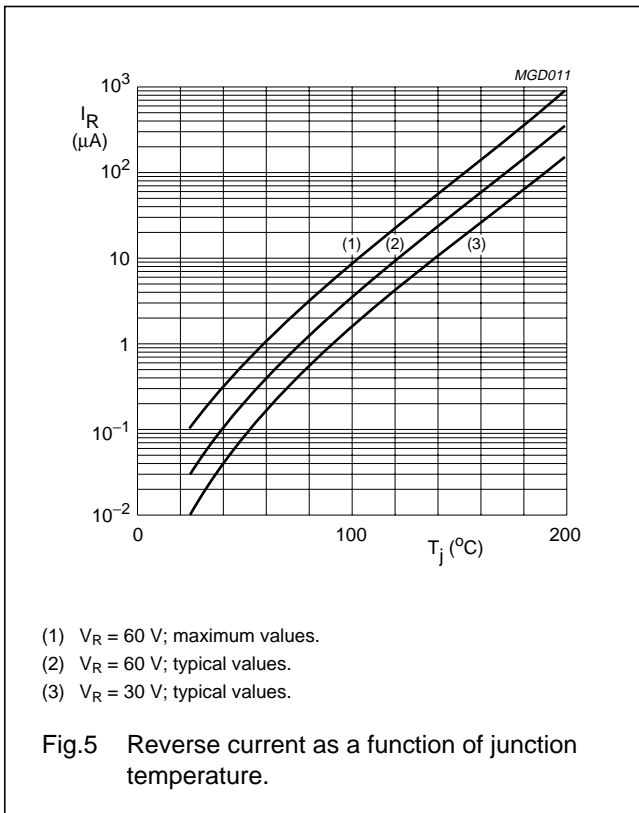
BAV10

GRAPHICAL DATA



High-speed diode

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High-speed diode

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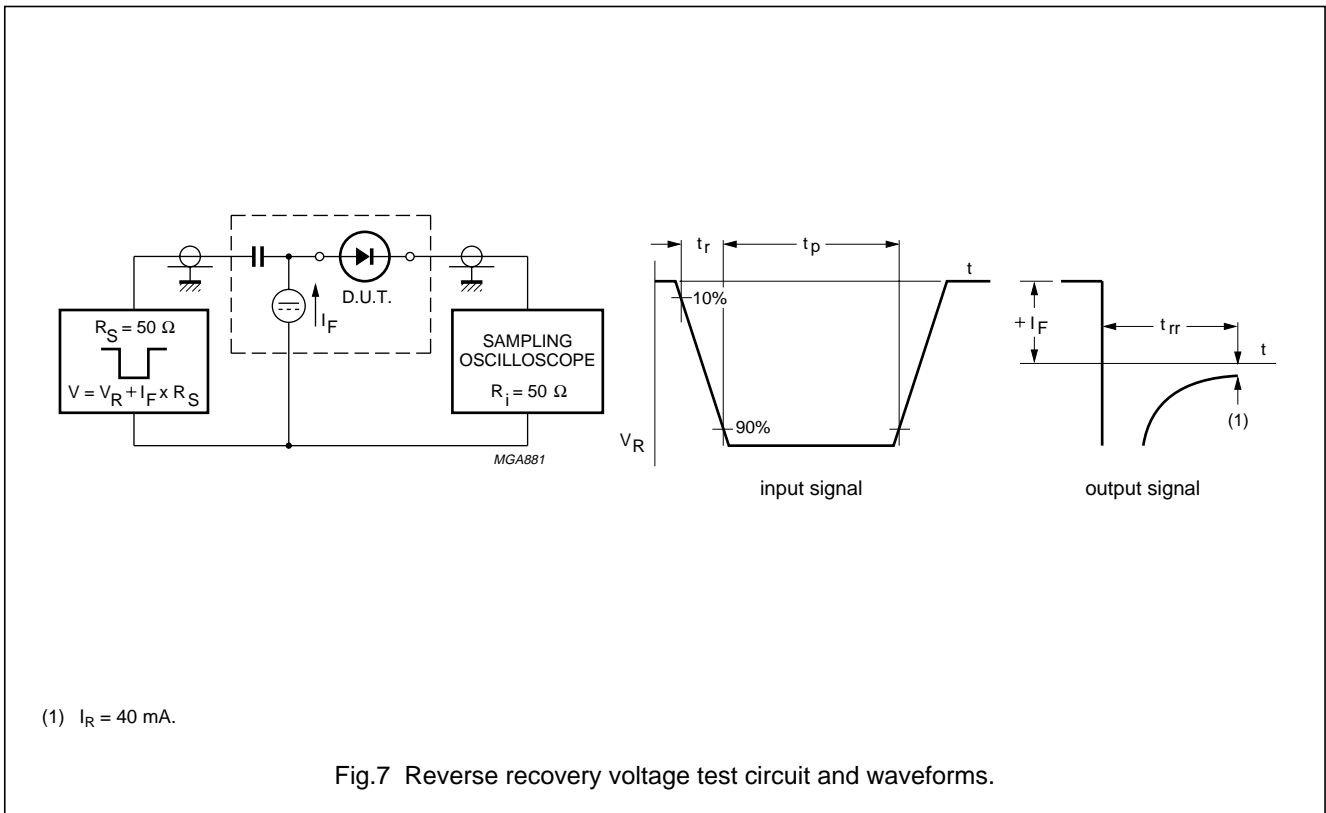
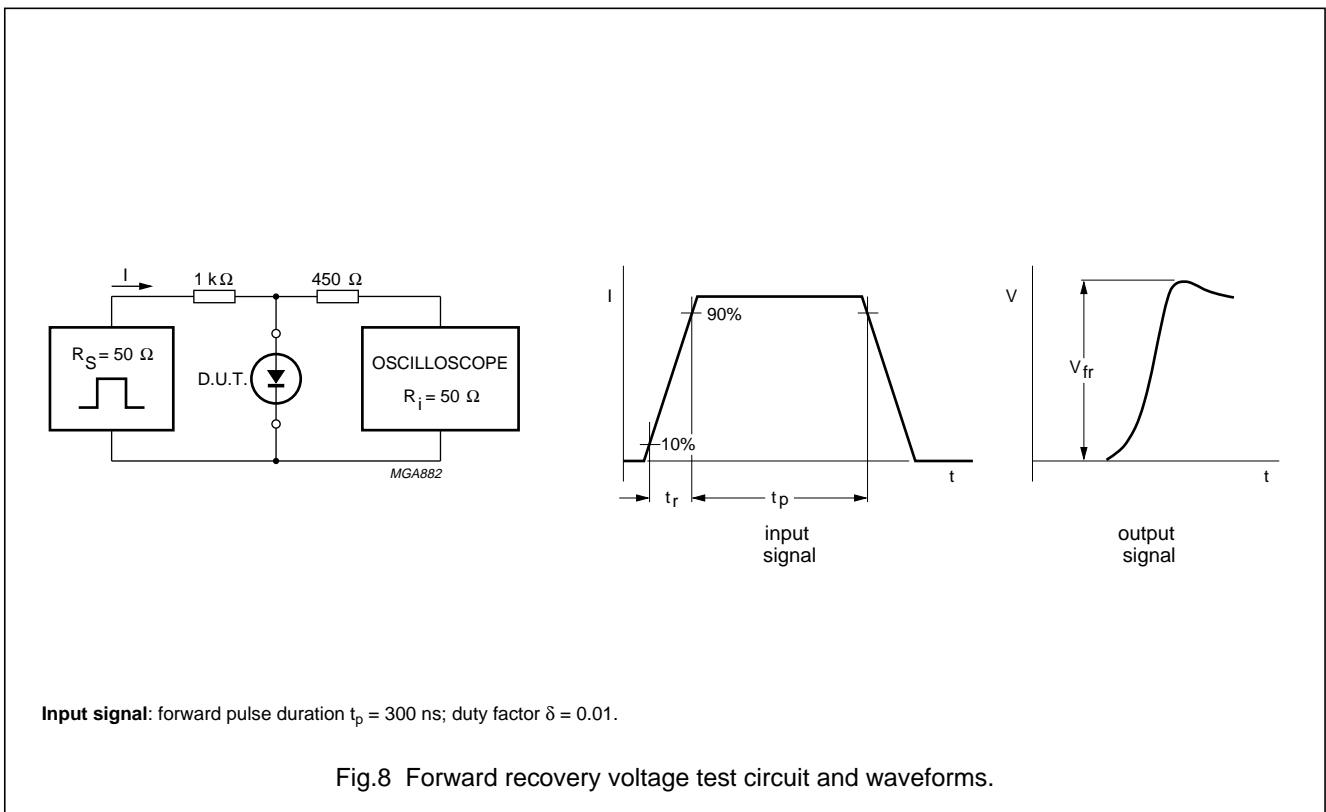


Fig.7 Reverse recovery voltage test circuit and waveforms.



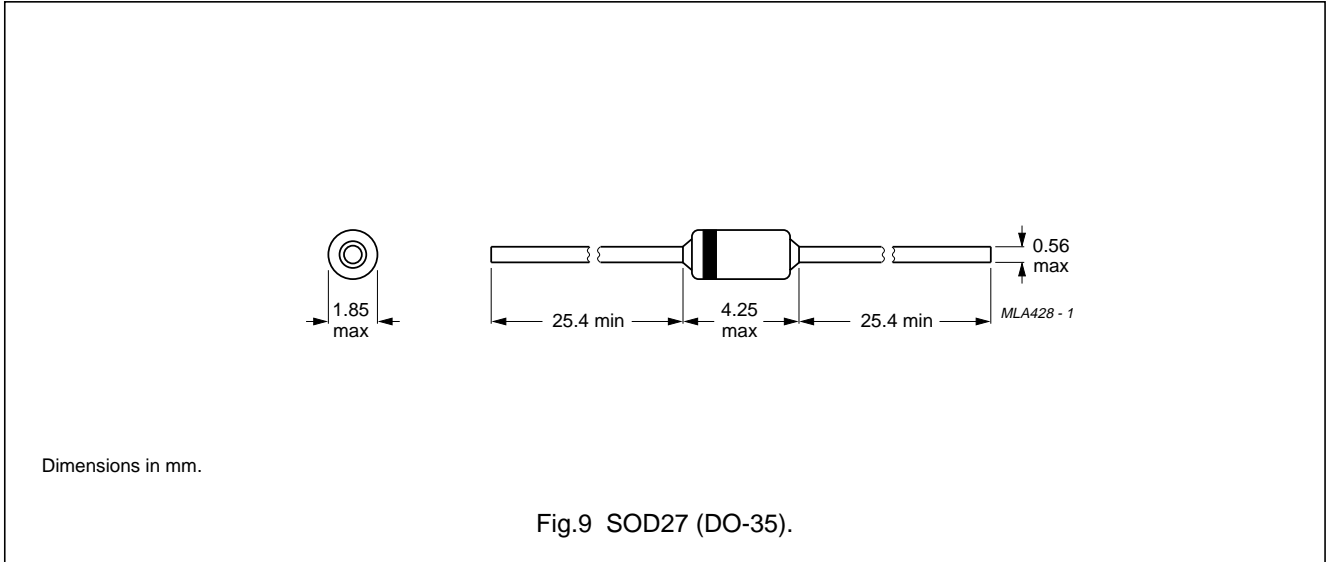
**Input signal:** forward pulse duration  $t_p = 300 \text{ ns}$ ; duty factor  $\delta = 0.01$ .

Fig.8 Forward recovery voltage test circuit and waveforms.

High-speed diode

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PACKAGE OUTLINE



DEFINITIONS

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.